**Product data sheet** 



## 1.1 General description

Hybrid high dynamic range amplifier module operating at a supply voltage of 24 V (DC) in a SOT115J package. The module consists of two cascaded stages both in cascode configuration.

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

#### 1.2 Features

- Excellent linearity
- Extremely low noise
- High gain
- Excellent return loss properties

## 1.3 Applications

Single module line extender in CATV systems operating in the 40 MHz to 750 MHz frequency range.

#### 1.4 Quick reference data

Table 1: Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	f = 50 MHz	33.2	-	35.2	dB
		f = 750 MHz	33.5	-	-	dB
I <sub>tot</sub>	total current consumption	$V_B = 24 \text{ V}$	[1] 285	-	325	mA

<sup>[1]</sup> The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.



# 2. Pinning information

Table 2: Pinning

	3	
Pin	Description	Simplified outline Symbol
1	input	
2	common	<u></u>
3	common	1 9
5	+V <sub>B</sub>	
7	common	
8	common	sym095
9	output	
-		

# 3. Ordering information

**Table 3: Ordering information** 

Type number	Package		
	Name	Description	Version
BGE788C	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 × 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J

# 4. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{B}$	supply voltage		-	25	V
Vi	RF input voltage		-	55	dBmV
T <sub>stg</sub>	storage temperature		-40	+100	°C
T <sub>mb</sub>	mounting base temperature		-20	+100	°C

# 5. Characteristics

**Table 5: Characteristics** 

Bandwidth 40 MHz to 750 MHz;  $V_B = 24$  V;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75$   $\Omega$ .

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	f = 50 MHz	33.2	-	35.2	dB
		f = 750 MHz	33.5	-	-	dB
SL	slope cable equivalent	f = 40 MHz to 750 MHz	0.3	-	2.3	dB
FL	flatness of frequency response	f = 40 MHz to 750 MHz	-	-	±0.6	dB
$ s_{11} ^2$	input return losses	f = 40 MHz to 320 MHz	16	-	-	dB
		f = 320 MHz to 640 MHz	15	-	-	dB
		f = 640 MHz to 750 MHz	14	-	-	dB
$ s_{22} ^2$	output return losses	f = 40 MHz to 320 MHz	16	-	-	dB
		f = 320 MHz to 640 MHz	15	-	-	dB
		f = 640 MHz to 750 MHz	14	-	-	dB
<b>φ</b> s21	phase response	f = 50 MHz	135	-	225	deg
СТВ	composite triple beat	110 channels flat; $V_0 = 44 \text{ dBmV}$ ; measured at 745.25 MHz	-	-	-49	dB
CSO	composite second order distortion	110 channels flat; $V_0 = 44 \text{ dBmV}$ ; measured at 746.5 MHz	-	-	-52	dB
NF	noise figure	f = 50 MHz	-	-	8	dB
I <sub>tot</sub>	total current consumption		<u>[1]</u> 285	-	325	mA

<sup>[1]</sup> The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

# 6. Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J

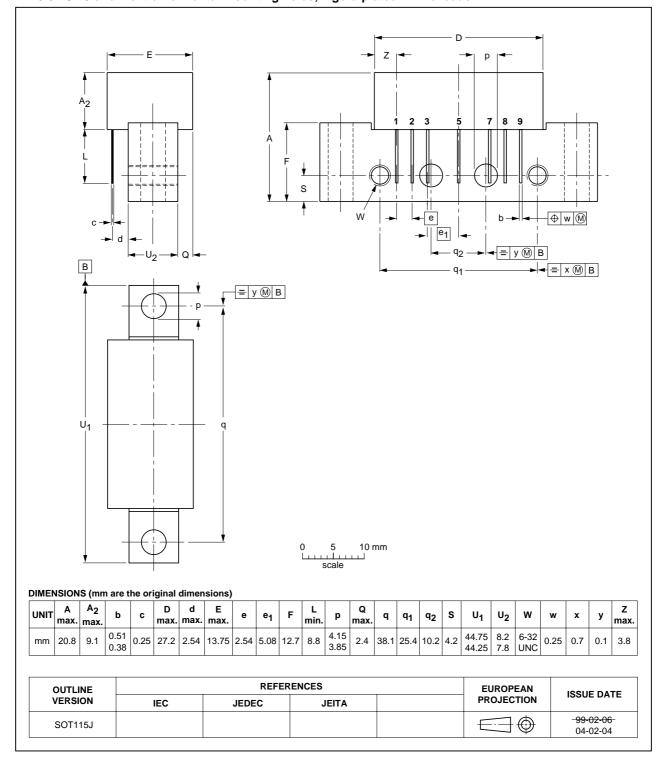


Fig 1. Package outline SOT115J

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# 7. Revision history

## Table 6: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BGE788C_1	20050401	Product data sheet	-	9397 750 14607	-



Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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- [2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- [3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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